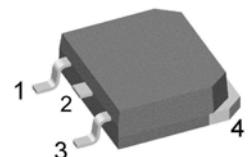


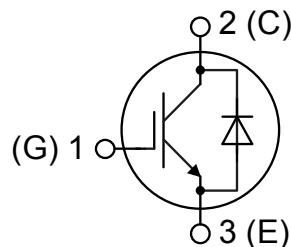
preliminary

**XPT IGBT**

$V_{CES}$  = 1200V  
 $I_{C25}$  = 9A  
 $V_{CE(sat)}$  = 1.8V

**Copack****Part number****IXA4IF1200TC**

Backside: collector

**Features / Advantages:**

- Easy paralleling due to the positive temperature coefficient of the on-state voltage
- Rugged XPT design (Xtreme light Punch Through) results in:
  - short circuit rated for 10  $\mu$ sec.
  - very low gate charge
  - low EMI
  - square RBSOA @ 3x  $I_c$
- Thin wafer technology combined with the XPT design results in a competitive low  $V_{CE(sat)}$
- SONIC™ diode
  - fast and soft reverse recovery
  - low operating forward voltage

**Applications:**

- AC motor drives
- Solar inverter
- Medical equipment
- Uninterruptible power supply
- Air-conditioning systems
- Welding equipment
- Switched-mode and resonant-mode power supplies
- Inductive heating, cookers
- Pumps, Fans

**Package:** TO-268AA (D3Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

## IGBT

Symbol	Definition	Conditions	min.	typ.	max.	Unit	
$V_{CES}$	collector emitter voltage	$T_{VJ} = 25^\circ C$			1200	V	
$V_{GES}$	max. DC gate voltage				$\pm 20$	V	
$V_{GEM}$	max. transient gate emitter voltage				$\pm 30$	V	
$I_{C25}$	collector current	$T_c = 25^\circ C$			9	A	
$I_{C100}$		$T_c = 100^\circ C$			5	A	
$P_{tot}$	total power dissipation	$T_c = 25^\circ C$			45	W	
$V_{CE(sat)}$	collector emitter saturation voltage	$I_c = 3A; V_{GE} = 15 V$	$T_{VJ} = 25^\circ C$	1.8	2.1	V	
					2.1	V	
$V_{GE(th)}$	gate emitter threshold voltage	$I_c = 0.1mA; V_{GE} = V_{CE}$	$T_{VJ} = 25^\circ C$	5.4	5.9	6.5	V
$I_{CES}$	collector emitter leakage current	$V_{CE} = V_{CES}; V_{GE} = 0 V$	$T_{VJ} = 25^\circ C$		0.1	mA	
					0.1	mA	
$I_{GES}$	gate emitter leakage current	$V_{GE} = \pm 20 V$			500	nA	
$Q_{G(on)}$	total gate charge	$V_{CE} = 600 V; V_{GE} = 15 V; I_c = 3 A$			12	nC	
$t_{d(on)}$	turn-on delay time	inductive load $V_{CE} = 600 V; I_c = 3 A$ $V_{GE} = \pm 15 V; R_G = 330 \Omega$	$T_{VJ} = 125^\circ C$	70		ns	
$t_r$	current rise time			40		ns	
$t_{d(off)}$	turn-off delay time			250		ns	
$t_f$	current fall time			100		ns	
$E_{on}$	turn-on energy per pulse			0.4		mJ	
$E_{off}$	turn-off energy per pulse			0.3		mJ	
<b>RBSOA</b>	reverse bias safe operating area	$V_{GE} = \pm 15 V; R_G = 330 \Omega$	$T_{VJ} = 125^\circ C$				
$I_{CM}$		$V_{CEmax} = 1200 V$			9	A	
<b>SCSOA</b>	short circuit safe operating area	$V_{CEmax} = 900 V$					
$t_{sc}$	short circuit duration	$V_{CE} = 900 V; V_{GE} = \pm 15 V$	$T_{VJ} = 125^\circ C$		10	μs	
$I_{sc}$	short circuit current	$R_G = 330 \Omega$ ; non-repetitive		12		A	
$R_{thJC}$	thermal resistance junction to case				2.7	K/W	
$R_{thCH}$	thermal resistance case to heatsink			0.15		K/W	

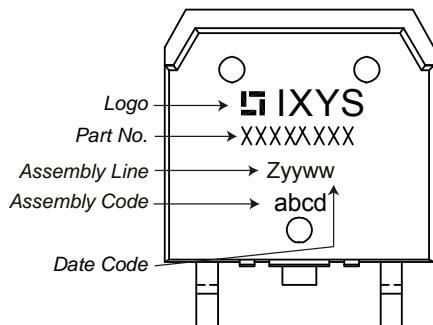
## Diode

$V_{RRM}$	max. repetitive reverse voltage	$T_{VJ} = 25^\circ C$		1200	V
$I_{F25}$	forward current	$T_c = 25^\circ C$		10	A
$I_{F100}$		$T_c = 100^\circ C$		6	A
$V_F$	forward voltage	$I_F = 3 A$	$T_{VJ} = 25^\circ C$	2.20	V
			$T_{VJ} = 125^\circ C$	1.90	V
$I_R$	reverse current	$V_R = V_{RRM}$	$T_{VJ} = 25^\circ C$	*	mA
	* not applicable, see $I_{CES}$ value above		$T_{VJ} = 125^\circ C$	*	mA
$Q_{rr}$	reverse recovery charge	$V_R = 600 V$ $-di_F/dt = -150 A/\mu s$ $I_F = 3 A; V_{GE} = 0 V$	$T_{VJ} = 125^\circ C$	0.5	μC
$I_{RM}$	max. reverse recovery current			5	A
$t_{rr}$	reverse recovery time			350	ns
$E_{rec}$	reverse recovery energy			0.1	mJ
$R_{thJC}$	thermal resistance junction to case			3	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.15	K/W

## Package TO-268AA (D3Pak)

Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			70	A
$T_{VJ}$	virtual junction temperature		-40		150	°C
$T_{op}$	operation temperature		-40		125	°C
$T_{stg}$	storage temperature		-40		150	°C
Weight				5		g
$F_c$	mounting force with clip		20		120	N

## Product Marking



## Part number

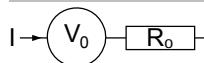
I = IGBT  
 X = XPT IGBT  
 A = Gen 1 / std  
 4 = Current Rating [A]  
 IF = Copack  
 1200 = Reverse Voltage [V]  
 TC = TO-268AA (D3Pak) (2)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	IXA4IF1200TC	IXA4IF1200TC	Tube	30	510224

Similar Part	Package	Voltage class
IXA4IF1200UC	TO-252AA (DPak)	1200

## Equivalent Circuits for Simulation

\* on die level

 $T_{VJ} = 150^\circ\text{C}$  $V_{0\max}$  threshold voltage $R_{0\max}$  slope resistance \*

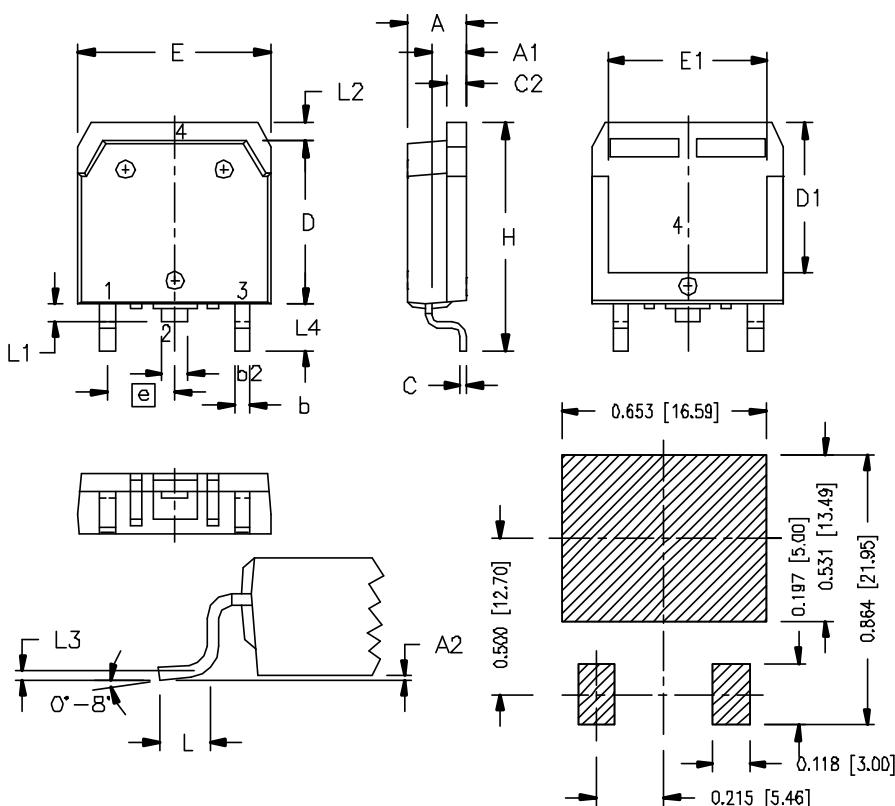
IGBT

Diode

1.1 1.25 V

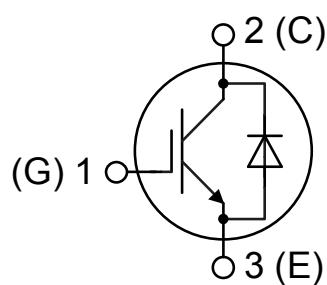
460 280 mΩ

## Outlines TO-268AA (D3Pak)



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.90	5.10	0.193	0.201
A1	2.70	2.90	0.106	0.114
A2	0.02	0.25	0.001	0.100
b	1.15	1.45	0.045	0.057
b2	1.90	2.10	0.075	0.083
C	0.40	0.65	0.016	0.026
C2	1.45	1.60	0.057	0.063
D	13.80	14.00	0.543	0.551
D1	12.40	12.70	0.488	0.500
E	15.85	16.05	0.624	0.632
E1	13.30	13.60	0.524	0.535
e	5.45 BSC		0.215 BSC	
H	18.70	19.10	0.736	0.752
L	2.40	2.70	0.094	0.106
L1	1.20	1.40	0.047	0.055
L2	1.00	1.15	0.039	0.045
L3	0.25 BSC		0.100 BSC	
L4	3.80	4.10	0.150	0.161

RECOMMENDED MINIMUM FOOT PRINT FOR SMD



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[GT50JR22\(STA1ES\)](#) [TIG058E8-TL-H](#) [IGW40N120H3FKSA1](#) [VS-CPV364M4KPBF](#) [NGTB25N120FL2WAG](#) [NGTG40N120FL2WG](#)  
[RJH60F3DPQ-A0#T0](#) [APT40GR120B2SCD10](#) [APT15GT120BRG](#) [APT20GT60BRG](#) [NGTB75N65FL2WAG](#) [NGTG15N120FL2WG](#)  
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